



**THE DATASHEET OF
FS6X1220RD**



FS6X1220R

Fairchild Power Switch (FPS™)

Features

- Current Mode PWM Control With a Fixed Operating Frequency (300kHz)
- Pulse by Pulse Current Limit
- Over Load Protection
- Over Voltage Protection
- Thermal Shutdown
- Built-in Auto-Restart Circuit
- Line Under Voltage Detection and Sleep on/off Function
- Internal High Voltage SenseFET (QFET)
- Supports Forward or Flyback Topology

Application

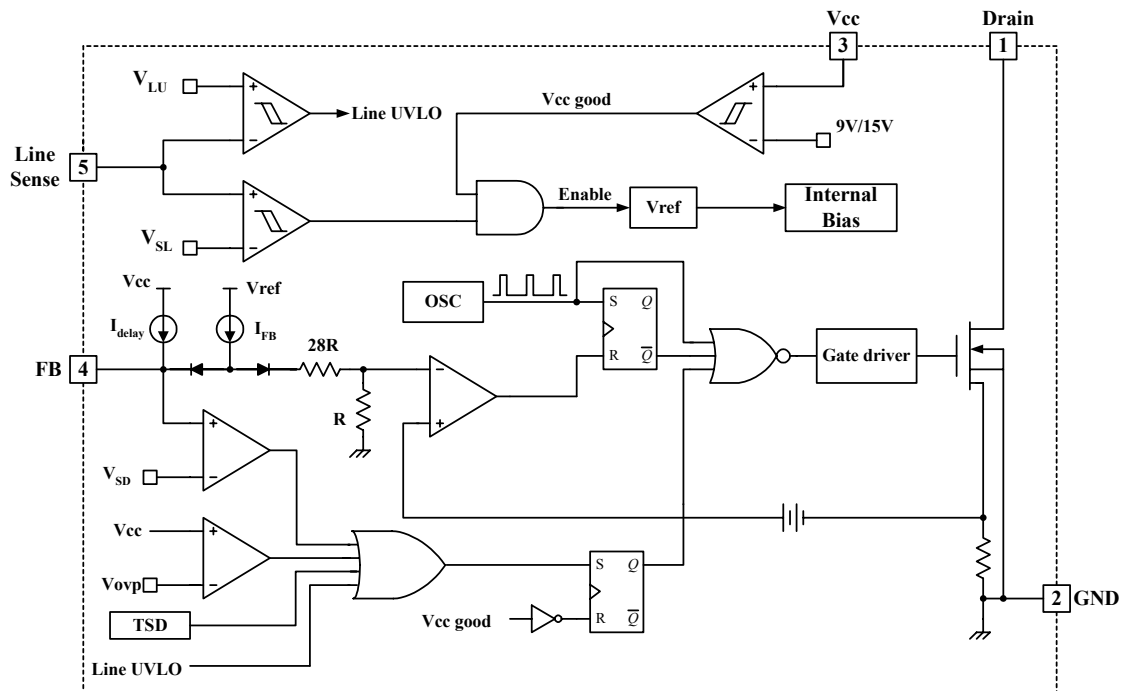
- DC-DC Converter

Description

The FS6X1220R is specially designed for an off-line DC-DC converters with minimal external components. This device is a current mode PWM controller combined with a high voltage power SenseFET in a single package. The PWM controller includes integrated fixed frequency oscillator, line under voltage lockout, sleep on/off function, thermal shutdown protection, over voltage protection, pulse-by-pulse current limit and temperature compensated precise current sources for a loop compensation. Compared with discrete MOSFET and PWM controller solution, the FS6X1220R can reduce total cost, component count, size and weight simultaneously increasing efficiency, productivity, and system reliability. This device is well suited for DC to DC converter applications up to 40W of output power.



Internal Block Diagram



Pin Description

| Pin Number | Pin Name | Pin Function Description |
|------------|-----------------|---|
| 1 | Drain | High voltage power SenseFET drain connection. |
| 2 | GND | This pin is the control ground and the SenseFET source. |
| 3 | Vcc | This pin is the positive supply input. This pin provides internal operating current for both start-up and steady-state operation. |
| 4 | Feedback (FB) | This pin is internally connected to the inverting input of the PWM comparator. The collector of an opto-coupler is typically tied to this pin. For stable operation, a capacitor should be placed between this pin and GND. If the voltage of this pin reaches 7.5V, the over load protection is activated resulting in shutdown of the IC. |
| 5 | Line Sense (LS) | According to the voltage of this pin, three operation modes are defined; Normal operation mode, Line under voltage lock out mode and Sleep mode. If the voltage of this pin is smaller than 2.55V, the IC goes into line under voltage lock out stopping switching operation. If the voltage of this pin is smaller than 1.8V, the IC enters into sleep mode. During sleep mode, reference voltage generation circuit including shunt regulator is disabled and only 300uA operation current is required. |

Absolute Maximum Ratings

(Ta=25°C, unless otherwise specified)

| Parameter | Symbol | Value | Unit |
|--|---------------------------|-------------------------|------|
| Drain-Gate Voltage (R _{GS} =1MΩ) | V _{DGR} | 200 | V |
| Gate-Source (GND) Voltage | V _{GS} | ±30 | V |
| Drain Current Pulsed ⁽²⁾ | I _{DM} | 32.8 | ADC |
| Single Pulsed Avalanche Energy ⁽³⁾ | E _{AS} | 210 | mJ |
| Continuous Drain Current (T _c = 25°C) | I _D | 8.2 | ADC |
| Continuous Drain Current (T _C =100°C) | I _D | 5.2 | ADC |
| Supply Voltage | V _{CC} | 35 | V |
| Input Voltage Range | V _{FB} | -0.3 to V _{CC} | V |
| | V _{LS} | -0.3 to V _{CC} | V |
| Total Power Dissipation | P _D (Watt H/S) | 45 | W |
| | Derating | 0.36 | W/°C |
| Operating Junction Temperature | T _j | +150 | °C |
| Operating Ambient Temperature | T _A | -25 to +85 | °C |
| Storage Temperature Range | T _{STG} | -55 to +150 | °C |

Notes:

1. T_j=25°C to 150°C
2. Repetitive rating: Pulse width limited by maximum junction temperature
3. L=4.7 mH, starting T_j=25°C

Electrical Characteristics (SenseFET part)

(Ta=25°C unless otherwise specified)

| Parameter | Symbol | Condition | Min. | Typ. | Max. | Unit |
|--|---------|---|------|------|------|------|
| Drain Source Breakdown Voltage | BVDSS | VGS=0V, ID=250μA | 200 | - | - | V |
| Zero Gate Voltage Drain Current | IDSS | VDS=200V, VGS=0V | - | - | 50 | μA |
| | | VDS=160V VGS=0V, TC=125°C | - | - | 200 | μA |
| Static Drain Source On Resistance ⁽¹⁾ | RDS(ON) | VGS=10V, ID=4.1A | - | 0.24 | 0.30 | Ω |
| Forward Transconductance | gfs | VDS=40V, ID=4.1A | - | 7.1 | - | mho |
| Input Capacitance | Ciss | VGS=0V, VDS=25V, f = 1MHz | - | 700 | 910 | pF |
| Output Capacitance | Coss | | - | 125 | 160 | |
| Reverse Transfer Capacitance | Crss | | - | 18 | 25 | |
| Turn On Delay Time | td(on) | VDD=100V, ID=11.6A (MOSFET switching time is essentially independent of operating temperature) | - | 13 | 35 | ns |
| Rise Time | tr | | - | 120 | 250 | |
| Turn Off Delay Time | td(off) | | - | 30 | 70 | |
| Fall Time | tf | | - | 55 | 120 | |
| Total Gate Charge (Gate-Source+Gate-Drain) | Qg | VGS=10V, ID=11.6A, VDS=160V (MOSFET switching time is essentially independent of operating temperature) | - | 18 | 23 | nC |
| Gate-Source Charge | Qgs | | - | 5 | - | |
| Gate-Drain (Miller) Charge | Qgd | | - | 8 | - | |

Note:

1. Pulse test : Pulse width ≤ 300μS, duty ≤ 2%

Electrical Characteristics (Continued)

(Ta=25°C unless otherwise specified)

| Parameter | Symbol | Condition | Min. | Typ. | Max. | Unit |
|--|----------------------|-----------------------------------|------|------|------|------|
| UVLO SECTION | | | | | | |
| Start Threshold Voltage | VSTART | VFB = GND | 14 | 15 | 16 | V |
| Stop Threshold Voltage | VSTOP | VFB = GND | 8 | 9 | 10 | V |
| OSCILLATOR SECTION | | | | | | |
| Initial Frequency | FOSC | - | 270 | 300 | 330 | kHz |
| Voltage Stability | FSTABLE | 12V ≤ VCC ≤ 23V | 0 | 1 | 3 | % |
| Temperature Stability (1) | ΔFOSC | -25°C ≤ Ta ≤ 85°C | 0 | ±5 | ±10 | % |
| Maximum Duty Cycle | DMAX | - | 72 | 80 | 88 | % |
| Minimum Duty Cycle | DMIN | - | - | - | 0 | % |
| FEEDBACK SECTION | | | | | | |
| Feedback Source Current | IFB | VFB = GND | 0.7 | 0.9 | 1.1 | mA |
| Shutdown Feedback Voltage | VSD | VFB ≥ 6.9V | 6.9 | 7.5 | 8.1 | V |
| Shutdown Delay Current | IDELAY | VFB = 5V | 4.0 | 5.0 | 6.0 | μA |
| LINE SENSE SECTION | | | | | | |
| Line UVLO Threshold Voltage | VLU | - | 2.4 | 2.55 | 2.7 | V |
| Sleep On/Off Threshold Voltage | VSL | - | 1.5 | 1.8 | 2.1 | V |
| CURRENT LIMIT(SELF-PROTECTION)SECTION | | | | | | |
| Peak Current Limit (2) | I _{OVER} | - | 2.82 | 3.2 | 3.58 | A |
| PROTECTION SECTION | | | | | | |
| Thermal Shutdown Temp (1) | TSD | - | 140 | 160 | - | °C |
| Over Voltage Protection | VOVP | V _{CC} ≥ 6.9V | 23 | 25 | 27 | V |
| TOTAL DEVICE SECTION | | | | | | |
| Start Up Current | I _{START} | VFB = GND, VCC = 14V | - | 60 | 120 | μA |
| Sleep Mode Current | I _{SLEEP} | V _{UVLO} = 1V, VCC = 16V | - | 300 | 500 | μA |
| Operating Supply Current | I _{OP} | VFB = GND, VCC = 16V | - | 10 | 15 | mA |
| | I _{OP(MIN)} | VFB = GND, VCC = 12V | | | | |
| | I _{OP(MAX)} | VFB = GND, VCC = 20V | | | | |

Note:

1. These parameters, although guaranteed at the design, are not tested in mass production.
2. These parameter indicates inductor current.

Typical Performance Characteristics

(These Characteristic Graphs are Normalized at Ta= 25°C)

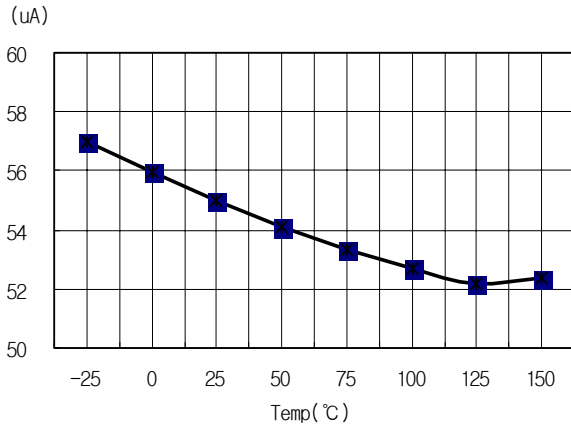


Figure 1. Start Up Current vs. Temp.

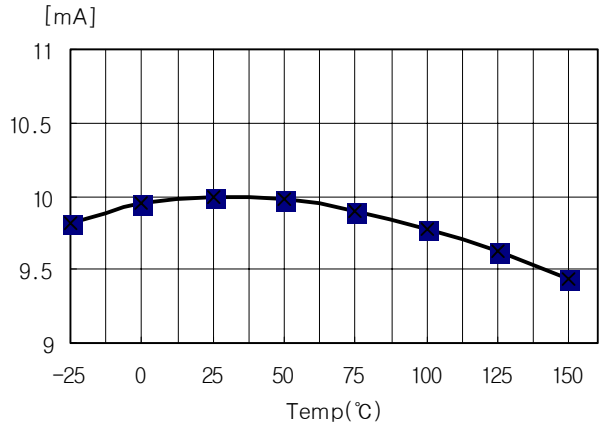


Figure 2. Operating Supply Current vs. Temp.

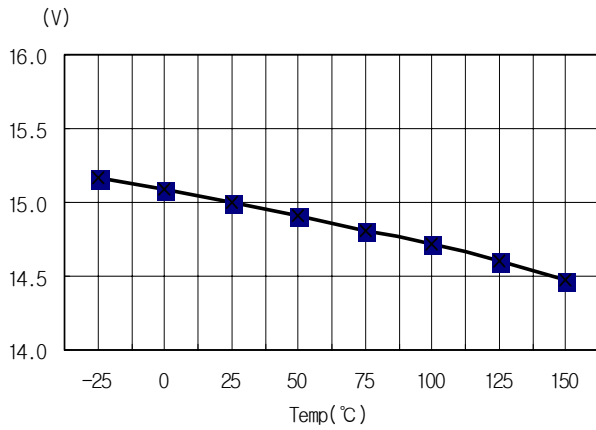


Figure 3. Start Threshold Voltage vs. Temp.

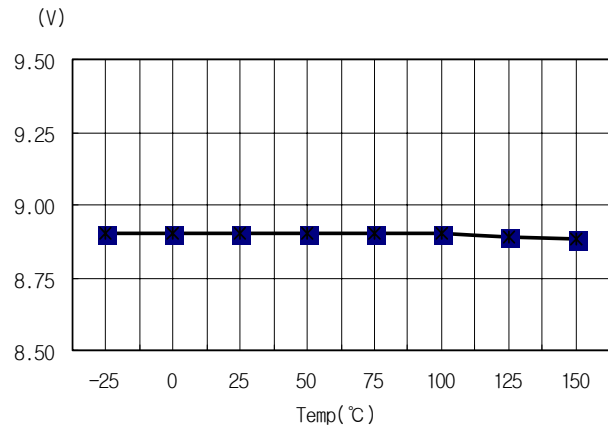


Figure 4. Stop Threshold Voltage vs. Temp.

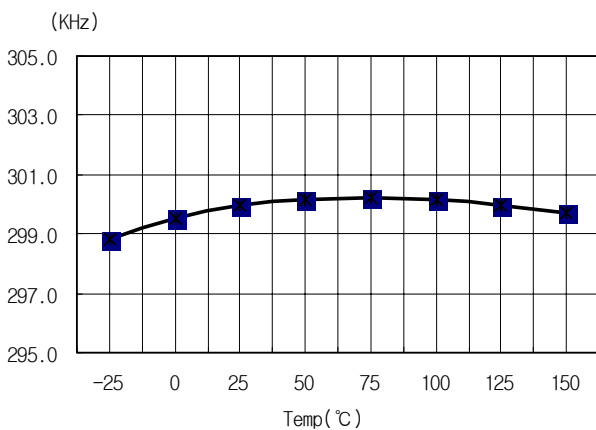


Figure 5. Initial Frequency vs. Temp.

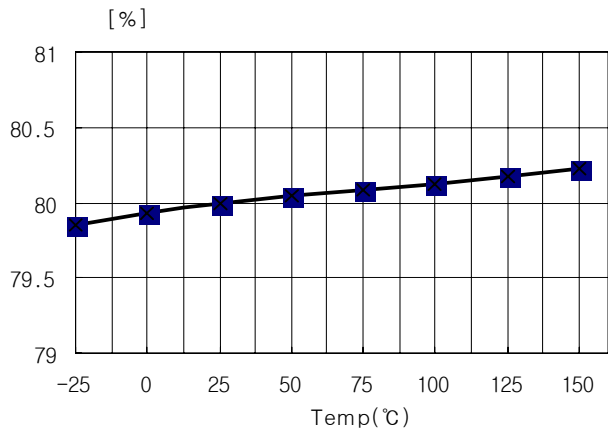


Figure 6. Maximum Duty vs. Temp.

Typical Performance Characteristics (Continued)

(These Characteristic Graphs are Normalized at Ta= 25°C)

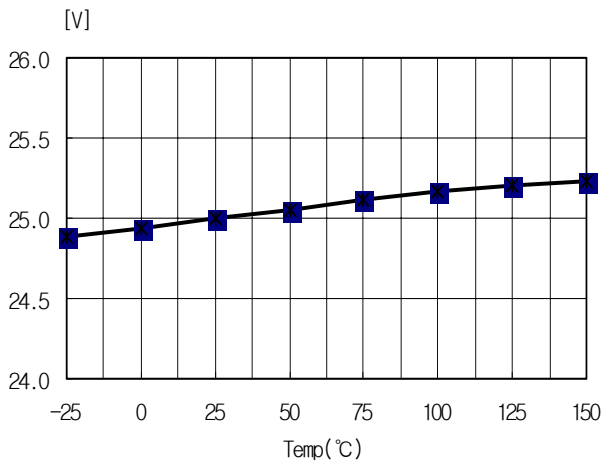


Figure 7. Over Voltage Protection vs. Temp.

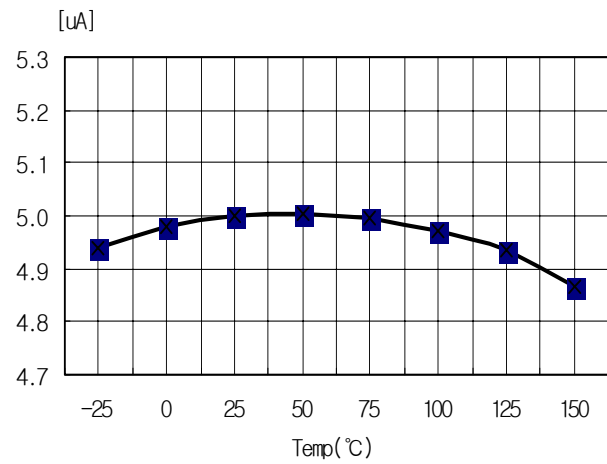


Figure 8. Shutdown Delay Current vs. Temp.

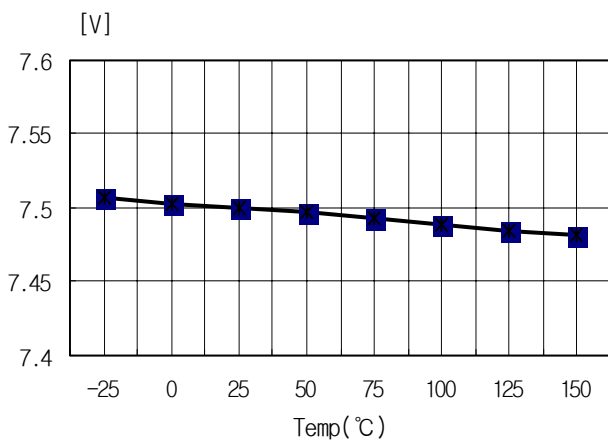


Figure 9. Shutdown Feedback Voltage vs. Temp.

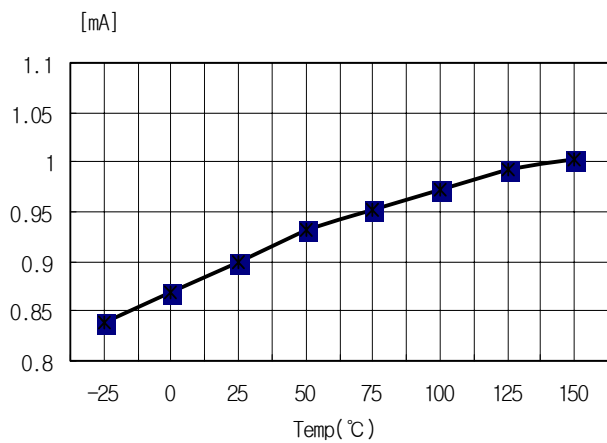


Figure 10. Feedback Source Current vs. Temp.

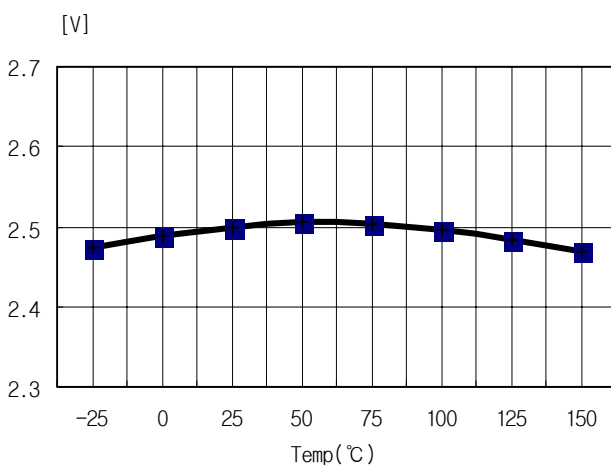


Figure 11. Line UVLO threshold voltage vs. Temp.

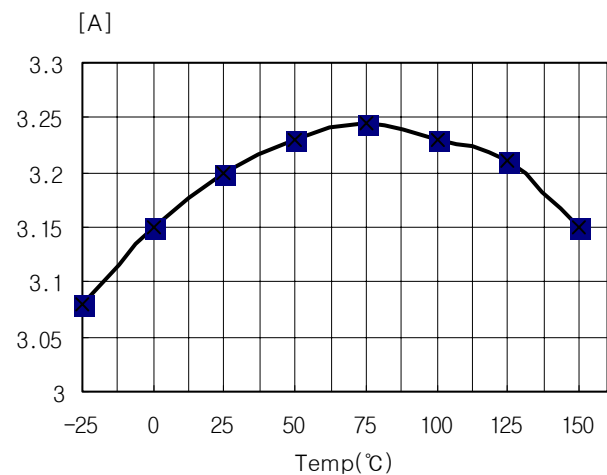


Figure 12. Peak Current Limit vs. Temp.

3.2 Over Load Protection (OLP) : Overload means that the load current exceeds a pre-set level due to an abnormal situation. In this situation, protection circuit should be activated in order to protect the SMPS. However, even when the SMPS is in the normal operation, the over load protection circuit can be activated during the load transition. In order to avoid this undesired operation, the over load protection circuit is designed to be activated after a specified period to determine whether it is a transient situation or an overload situation. Because of the pulse-by-pulse current limit capability, the maximum peak current through the SMPS is limited, and therefore the maximum input power is restricted with a given input voltage. If the output consumes beyond this maximum power, the output voltage (V_o) decreases below the set voltage. This reduces the current through the opto-coupler diode, which also reduces opto-coupler transistor current increasing V_{fb} . If V_{fb} exceeds 2.6V, D1 is blocked and the $5\mu\text{A}$ current source starts to charge C_{fb} slowly compared to when the 0.9mA current source charges C_{fb} . In this condition, V_{fb} continues increasing until it reaches 7.5V, and the switching operation is terminated at that time as shown in figure 4. The delay time for shutdown is the time required to charge C_{fb} from 2.6V to 7.5V with $5\mu\text{A}$. When C_{fb} is 10nF (103), T_{12} is approximately 9.8ms and when C_{fb} is $0.1\mu\text{F}$ (104), T_{12} is approximately 98ms. These values are enough to prevent SMPS from being shut down during transient situations.

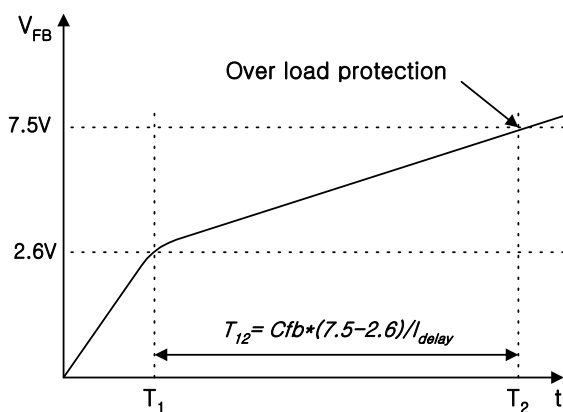


Figure 4. Over load protection

3.3 Over voltage Protection (OVP) : In case of malfunction in the secondary side feedback circuit, or feedback loop open caused by a defect of solder, the current through the opto-coupler transistor becomes almost zero. Then, V_{fb} climbs up in a similar manner to the over load situation, forcing the preset maximum current to be supplied to the secondary side until the over load protection is activated. Because energy more than required is provided to the output, the output voltage may exceed the rated voltage before the over load protection is activated, resulting in the breakdown of the devices in the secondary side. In order to prevent this situation, an over voltage protection (OVP) circuit is employed. In general, V_{cc} is proportional to the output

voltage and FS6X1220R uses V_{cc} instead of directly monitoring the output voltage. If V_{CC} exceeds 25V, OVP circuit is activated resulting in termination of switching. In order to avoid undesired activation of OVP during normal operation, V_{cc} should be properly designed to be below 25V.

3.4 Thermal Shutdown (TSD) : The thermal shutdown circuitry senses the junction temperature. The threshold is set at 160°C . When the junction temperature rises above this threshold (160°C) the power MOSFET is disabled.

4. The Line UVLO and Sleep Mode

According to the voltage of Line Sense pin, three operation modes are defined; Normal operation mode, Line under voltage lock out mode and Sleep mode as shown in figure 5. When the voltage of this pin is over 2.55V, FS6X1220R operates in normal mode. When the voltage of this pin is smaller than 2.55V, it goes into line under voltage lock out mode terminating switching operation. When the voltage of this pin is smaller than 1.8V, it enters into sleep mode. During sleep mode, reference voltage generation circuit including shunt regulator is disabled and only $300\mu\text{A}$ operation current is required.

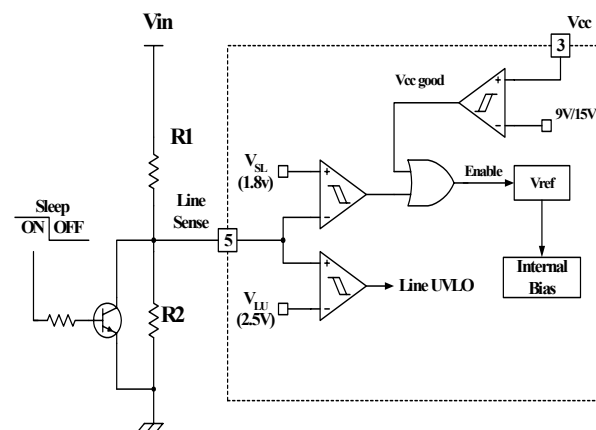
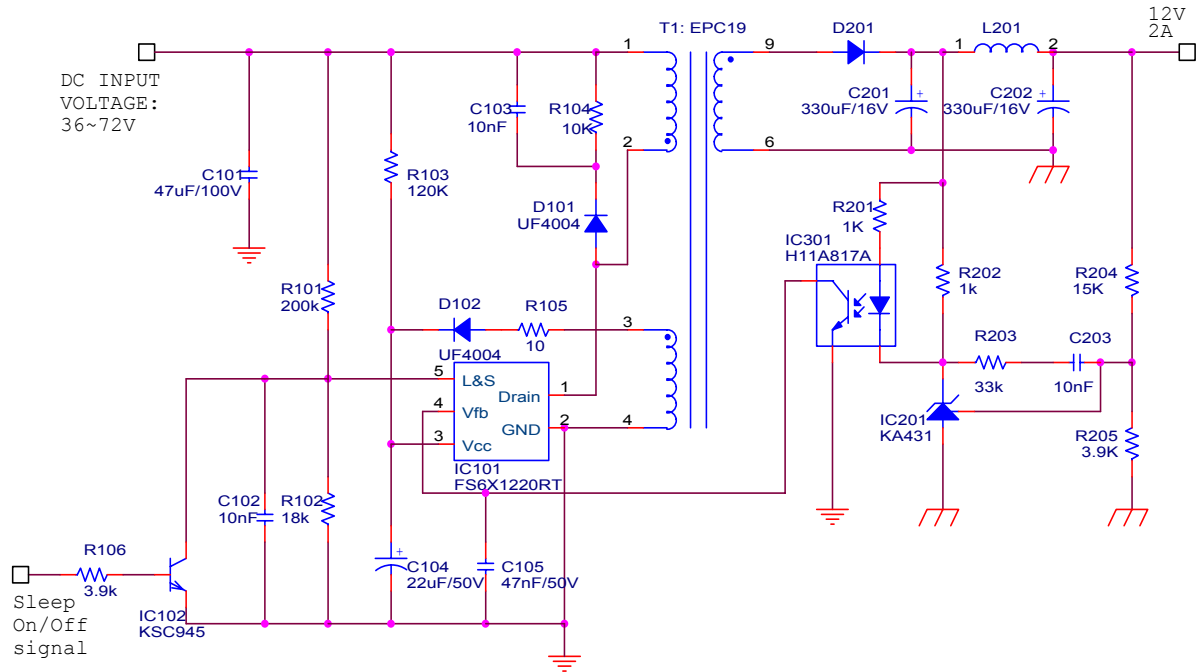


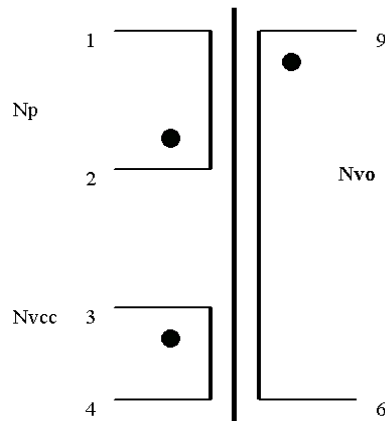
Figure 5. Line Sense block

Typical Application Circuit

1. Application circuit for DC-DC converter (Flyback)



2. Transformer Schematic Diagram



3.Winding Specification

| Name | Pin (s→f) | Wire | Turns | Winding Method |
|---|-----------|----------------|-------|------------------|
| Np ¹ | 2 → 1 | 0.3 ϕ × 1 | 20 | Solenoid Winding |
| Insulation: Polyester Tape t = 0.050mm, 2Layers | | | | |
| Nvo | 9 → 6 | 0.3 ϕ × 2 | 12 | Solenoid Winding |
| Insulation: Polyester Tape t = 0.050mm, 2Layers | | | | |
| Nvcc | 3 → 4 | 0.2 ϕ × 1 | 18 | Solenoid Winding |
| Insulation: Polyester Tape t = 0.050mm, 2Layers | | | | |
| Np ² | 2 → 1 | 0.3 ϕ × 1 | 20 | Solenoid Winding |
| Outer Insulation: Polyester Tape t = 0.050mm, 2Layers | | | | |

4.Electrical Characteristics

| | Pin | Specification | Remarks |
|--------------------|-------|---------------|---------------------------|
| Inductance | 1 - 2 | 28uH ± 10% | 300kHz, 1V |
| Leakage Inductance | 1 - 2 | 2uH Max | 2 nd all short |

5. Core & Bobbin

Core : EPC 19

Bobbin : EPC 19

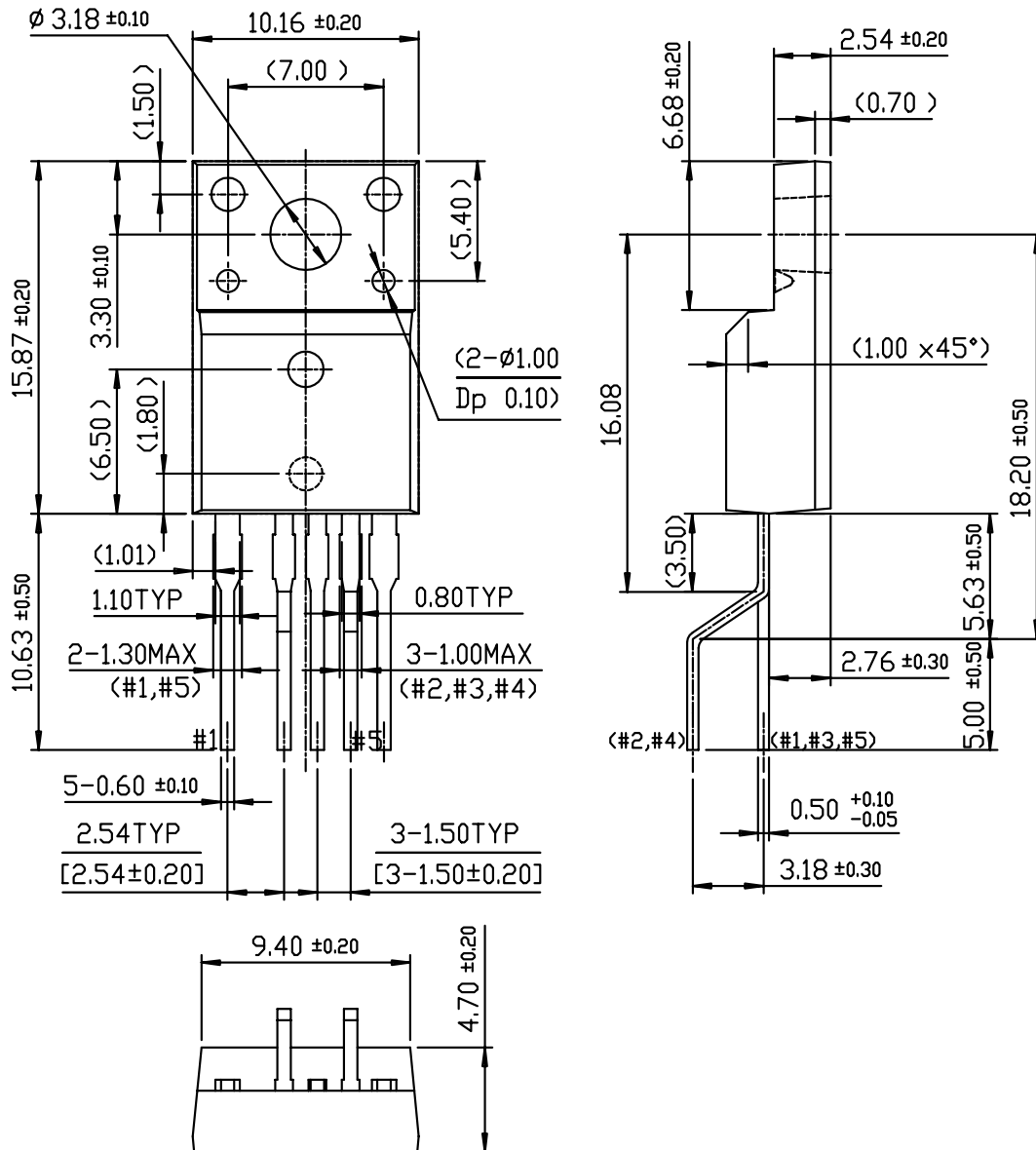
Ae(mm²) : 22.7

6.Demo Circuit Part List

| Part | Value | Note | Part | Value | Note |
|------------------|------------|------------------------|--------------|--------------|------------------------|
| Resistor | | | C201 | 330uF/16V | Electrolytic Capacitor |
| R101 | 200K, 1/4W | - | C202 | 330uF/16V | Electrolytic Capacitor |
| R102 | 18K, 1/4W | - | C203 | 10nF/50V | Ceramic Capacitor |
| R103 | 120K, 1/4W | - | - | - | - |
| R104 | 10K, 1/4W | - | - | - | - |
| R105 | 10, 1/4W | - | Diode | | |
| R106 | 3.9K, 1/4W | - | D101 | UF4004 | - |
| R201 | 1K, 1/4W | - | D102 | UF4004 | - |
| R202 | 1K, 1/4W | - | D201 | MBRF10100 | - |
| R203 | 33K, 1/4W | - | - | - | - |
| R204 | 15K, 1/4W | - | IC | | |
| R205 | 3.9K, 1/4W | - | IC101 | FS6X1220RT | (3.2A, 200V) |
| Capacitor | | | IC102 | KSC945 | npn transistor |
| C101 | 47uF, 100V | Electrolytic Capacitor | IC201 | KA431(LM431) | Voltage reference |
| C102 | 10nF, 50V | Ceramic Capacitor | PC | H11A817A | Photo coupler / QT |
| C103 | 10nF, 200V | Ceramic Capacitor | - | - | - |
| C104 | 22uF, 50V | Electrolytic Capacitor | - | - | - |
| C105 | 47nF, 50V | Ceramic Capacitor | - | - | - |

Package Dimensions

TO-220F-5L(Forming)



Ordering Information

| Product Number | Package | Marking Code | BVdss | Rds(on) ^{Max.} |
|----------------|---------------------|--------------|-------|-------------------------|
| FS6X1220RTYDTU | TO-220F-5L(Forming) | 6X1220R | 200V | 0.30Ω |
| FS6X1220RD | D2-PAK-5L | | | |

YDTU : Forming Type

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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